

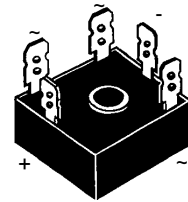
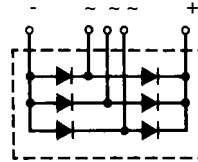
# Three Phase Rectifier Bridges with Semi Fast Diodes

$$I_{dAVM} = 18 \text{ A}$$

$$V_{RRM} = 1200-1600 \text{ V}$$

## Preliminary Data

| $V_{RSM}$<br>V | $V_{RRM}$<br>V | Type         |
|----------------|----------------|--------------|
| 1200           | 1200           | VUO 18-12DT8 |
| 1400           | 1400           | VUO 18-14DT8 |
| 1600           | 1600           | VUO 18-16DT8 |



| Symbol     | Test Conditions                               | Maximum Ratings          | Features  |
|------------|---|--------------------------|---|
| $I_{dAV}$  | $T_C = 85^\circ\text{C}$ , module             | 14 A                     | <ul style="list-style-type: none"> <li>• Package with 1/4" fast-on terminals</li> <li>• Isolation voltage 3000 V~</li> <li>• Planar passivated chips</li> <li>• Blocking voltage up to 1600 V</li> <li>• Low forward voltage drop</li> <li>• UL registered E 72873</li> </ul> |
| $I_{dAVM}$ | $T_C = 63^\circ\text{C}$ , module             | 18 A                     |   |
| $I_{FSM}$  | $T_{VJ} = 45^\circ\text{C}$ ;<br>$V_R = 0$    | t = 10 ms (50 Hz), sine  | 300 A   |
|            |   | t = 8.3 ms (60 Hz), sine | 330 A   |
| $I^2t$     | $T_{VJ} = T_{VJM}$<br>$V_R = 0$               | t = 10 ms (50 Hz), sine  | 270 A   |
|            |   | t = 8.3 ms (60 Hz), sine | 300 A   |
| $I^2t$     | $T_{VJ} = 45^\circ\text{C}$<br>$V_R = 0$      | t = 10 ms (50 Hz), sine  | 450 A <sup>2</sup> s  |
|            |   | t = 8.3 ms (60 Hz), sine | 460 A <sup>2</sup> s  |
| $T_{VJ}$   | $V_R = 0$                                     | t = 10 ms (50 Hz), sine  | 365 A <sup>2</sup> s  |
|            |   | t = 8.3 ms (60 Hz), sine | 380 A <sup>2</sup> s  |
| $T_{VJM}$  |   | -40...+150 °C            |   |
| $T_{stg}$  |   | 150 °C                   |   |
| $V_{ISOL}$ | 50/60 Hz, RMS<br>$I_{ISOL} \leq 1 \text{ mA}$ | t = 1 min                | 2500 V~   |
|            |   | t = 1 s                  | 3000 V~   |
| $M_d$      | Mounting torque (M5)<br>(10-32 UNF)           |                          | 2 ± 10 % Nm   |
|            |   |                          | 18 ± 10 % lb.in.  |
| Weight     | typ.  |                          | 22 g  |

## Features

- Package with 1/4" fast-on terminals
- Isolation voltage 3000 V~
- Planar passivated chips
- Blocking voltage up to 1600 V
- Low forward voltage drop
- UL registered E 72873

## Applications

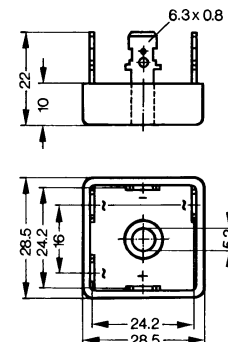
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature and power cycling
- **Up to 10 dB lower EMI/RFI compared to standard rectifier**

| Symbol     | Test Conditions   | Characteristic Values |
|------------|---|-----------------------|
| $I_R$      | $T_{VJ} = 25^\circ\text{C}$ ; $V_R = V_{RRM}$   | ≤ 0.3 mA              |
|            | $T_{VJ} = 125^\circ\text{C}$ ; $V_R = V_{RRM}$  | ≤ 5.0 mA              |
| $V_F$      | $I_F = 55 \text{ A}$ ; $T_{VJ} = 25^\circ\text{C}$  | ≤ 1.85 V              |
| $V_{T0}$   | For power-loss calculations only  | 1.2 V                 |
| $r_T$      | $T_{VJ} = T_{VJM}$  | 16 mΩ                 |
| $t_{rr}$   | $T_{VJ} = 25^\circ\text{C}$ ; $I_F = 10 \text{ A}$ ;<br>-di/dt = 10 A/μs, $V_R = 1/2 V_{RRM}$ | ≤ 1.5 μs              |
| $R_{thJC}$ | per diode; 120° el  | 9.3 K/W               |
|            | per module  | 1.55 K/W              |
| $R_{thJK}$ | per diode; 120° e   | 10.2 K/W              |
|            | per module  | 1.7 K/W               |
| $d_s$      | Creeping distance on surface  | 12.7 mm               |
| $d_A$      | Creepage distance in air  | 9.4 mm                |
| $a$        | Max. allowable acceleration   | 50 m/s <sup>2</sup>   |

## Dimensions in mm (1 mm = 0.0394")



Data according to IEC 60747